

DESCRIPTION

The GC1600 series varactors are silicon abrupt junction devices. They offer the highest Q and lowest series resistance available in a 45 Volt silicon varactor.

This series of diodes meets RoHS requirements per EU Directive 2002/95/EC. The standard terminal finish is gold unless otherwise specified. Consult the factory if you have special requirements.

KEY FEATURES

- Highest Q for 45 Volt Varactors
- Lowest R_s
- Large selection of capacitance values to choose from
- Low phase noise
- RoHS Compliant¹

APPLICATIONS

The GC1600 series varactors are used for narrow to moderate bandwidth tuning. They are available in values appropriate for VHF through KU band frequencies. These devices are best used in low phase noise voltage controlled oscillators, low loss voltage variable filters and phase shifters.

Standard capacitance tolerance is $\pm 10\%$ other capacitance values and custom mechanical configurations are also available. All specifications shown are based on style 30 package and include 0.18 pF case capacitance. Consult package outline section of this catalog for other case styles available. Complete electrical and mechanical data is also provided.

¹ Most of our devices are supplied with Gold plated terminations. Other terminal finishes are available on request. Consult factory for details.

APPLICATIONS/BENEFITS

- VHF to Ku Band Tuning
- VVF (Voltage Variable Filters)
- Phase Shifters

ABSOLUTE MAXIMUM RATINGS AT 25° C (UNLESS OTHERWISE SPECIFIED)

Rating	Symbol	Value	Unit
Minimum Breakdown Voltage @10 μ A	V_B	45	V
Maximum Leakage Current @35 Volts	I_R	0.02 @ 25 °C 2.0 @125 °C	μ A
Operating Temperature	T_{OP}	-55 to +125	°C
Storage Temperature	T_{STG}	-65 to +150	°C
Thermal Coefficient of Capacitance @4 Volts	T_{CC}	300	ppm/ °C

IMPORTANT: For the most current data, consult MICROSEMI's website: www.microsemi.com
 Specifications are subject to change, consult the factory for further information.



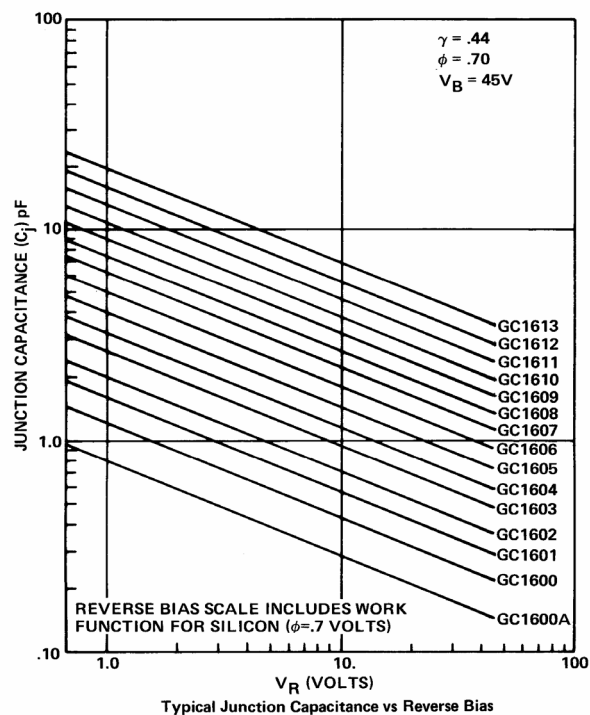
These devices are ESD sensitive and must be handled using ESD precautions.

ELECTRICAL CHARACTERISTICS @ 25° C

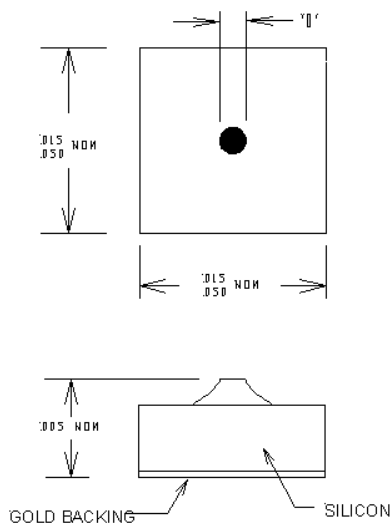
Model Number	C_{T-4} + / - 10%	Quality Factor ³ (Min)	Capacitance Ratio ² (Min)
	(Note 2) @ -4V (pF)	@-4V, 50 MHz	C_{T0} / C_{T-45}
GC1600A – 00	0.6	3000	4.0
GC1600 – 30	0.8	2900	4.2
GC1601 – 30	1.0	2800	4.4
GC1602 – 30	1.2	2800	4.5
GC1603 – 30	1.5	2300	4.8
GC1604 – 30	1.8	2000	4.9
GC1605 – 30	2.2	2000	5.0
GC1606 – 30	2.7	1900	5.2
GC1607 – 30	3.3	1900	5.3
GC1608 – 30	3.9	1900	5.4
GC1609 – 30	4.7	1500	5.4
GC1610 – 30	5.6	1700	5.5
GC1611 – 30	6.8	1700	5.5
GC1612 – 30	8.2	1500	5.6
GC1613 – 30	10.0	1500	5.6

Notes

- 1) When ordering, specify the desired case style suffix to the model. (eg. GC1601 – 30)
- 2) Capacitance values include a package capacitance of 0.18 pF. Capacitance is measured at F = 1 MHz.
- 3) Q is calculated from:
 - a. $Q = 1 / 2\pi f R_s C_j$
 - b. R_s is measured using @ 1 GHz using transmission loss techniques.
 - c. Capacitance is measured at 1 MHz

TYPICAL CJ VS REVERSE BIAS
NOTES


- CHIP DIMENSIONS VARY BY PRODUCT
- OTHER PACKAGE STYLES AVAILABLE ON REQUEST
- CONSULT FACTORY FOR DETAILS

STYLE 00
STYLE 30

NOTES:

1. TOP CONTACT, CHIP SIZE, AND CHIP THICKNESS DEPENDS ON DIODE PARAMETERS. CONSULT FACTORY.
2. TOP AND BOTTOM CONTACTS GOLD.

